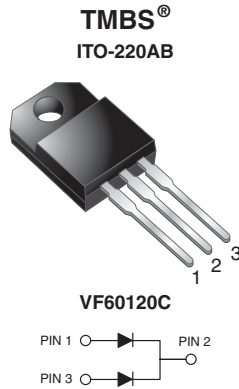


## Dual High-Voltage Trench MOS Barrier Schottky Rectifier

Ultra Low  $V_F = 0.41\text{ V}$  at  $I_F = 5\text{ A}$



### FEATURES

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- High efficiency operation
- Low thermal resistance
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC
- **Halogen-free according to IEC 61249-2-21 definition**



**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### TYPICAL APPLICATIONS

For use in high frequency converters, switching power supplies, freewheeling diodes, OR-ing diode, DC/DC converters and reverse battery protection.

### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	2 x 30 A
$V_{RRM}$	120 V
$I_{FSM}$	300 A
$V_F$ at $I_F = 30\text{ A}$	0.71 V
$T_J$ max.	150 °C

### MECHANICAL DATA

**Case:** ITO-220AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

**Polarity:** As marked

**Mounting Torque:** 10 in-lbs maximum

### MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)

PARAMETER	SYMBOL	VF60120C	UNIT
Maximum repetitive peak reverse voltage	$V_{RRM}$	120	V
Maximum average forward rectified current (fig. 1)	$I_{F(AV)}$	per device	60
		per diode	30
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode	$I_{FSM}$	300	A
Isolation voltage from terminal to heatsink $t = 1$	$V_{AC}$	1500	V
Voltage rate of change (rated $V_R$ )	$dV/dt$	10 000	V/ $\mu$ s
Operating junction and storage temperature range	$T_J, T_{STG}$	- 40 to + 150	°C



ELECTRICAL CHARACTERISTICS ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	$I_F = 5\text{ A}$	$T_A = 25\text{ }^\circ\text{C}$	$V_F^{(1)}$	0.48	-	V
	$I_F = 15\text{ A}$			0.66	-	
	$I_F = 30\text{ A}$			0.88	0.95	
	$I_F = 5\text{ A}$	$T_A = 125\text{ }^\circ\text{C}$		0.41	-	
	$I_F = 15\text{ A}$			0.58	-	
	$I_F = 30\text{ A}$			0.71	0.75	
Reverse current at rated $V_R$ per diode	$V_R = 90\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$	$I_R^{(2)}$	14	-	$\mu\text{A}$
		$T_A = 125\text{ }^\circ\text{C}$		11	-	mA
	$V_R = 120\text{ V}$	$T_A = 25\text{ }^\circ\text{C}$		40	500	$\mu\text{A}$
		$T_A = 125\text{ }^\circ\text{C}$		15	45	mA

Notes

- (1) Pulse test: 300  $\mu\text{s}$  pulse width, 1 % duty cycle
- (2) Pulse test: Pulse width  $\leq 40\text{ ms}$

THERMAL CHARACTERISTICS ( $T_A = 25\text{ }^\circ\text{C}$ unless otherwise noted)				
PARAMETER		SYMBOL	VF60120C	UNIT
Typical thermal resistance	per diode	$R_{\theta JC}$	5.0	$^\circ\text{C/W}$
	per device		3.8	

ORDERING INFORMATION (Example)					
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
ITO-220AB	VF60120C-M3/4W	1.76	4W	50/tube	Tube

RATINGS AND CHARACTERISTICS CURVES

( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

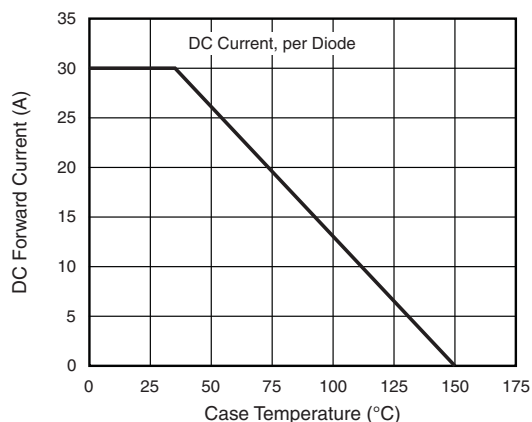


Fig. 1 - Maximum Forward Current Derating Curve

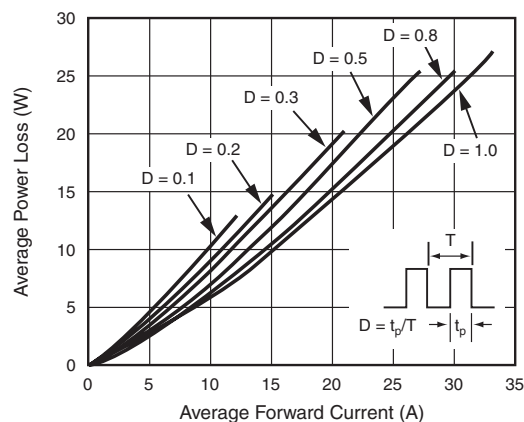


Fig. 2 - Forward Power Loss Characteristics Per Diode

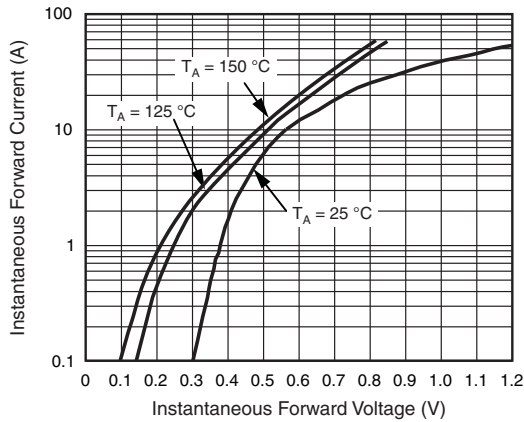


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

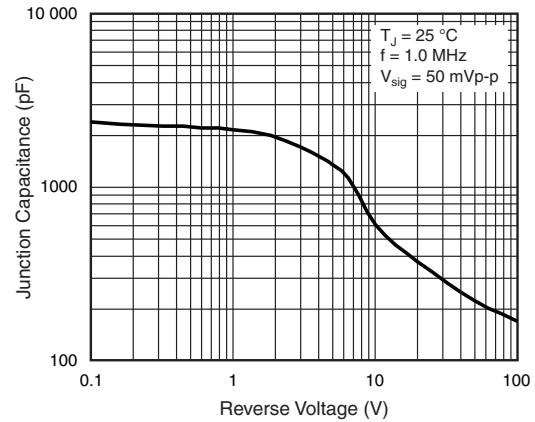


Fig. 5 - Typical Junction Capacitance Per Diode

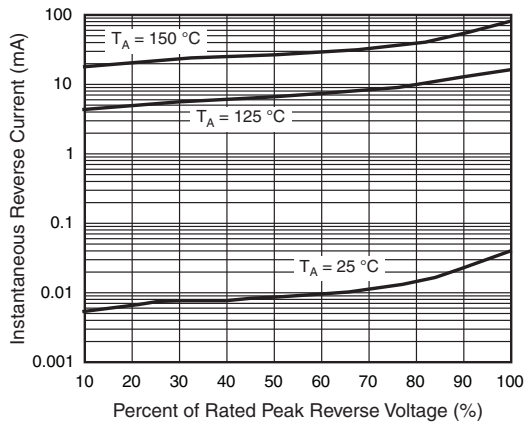
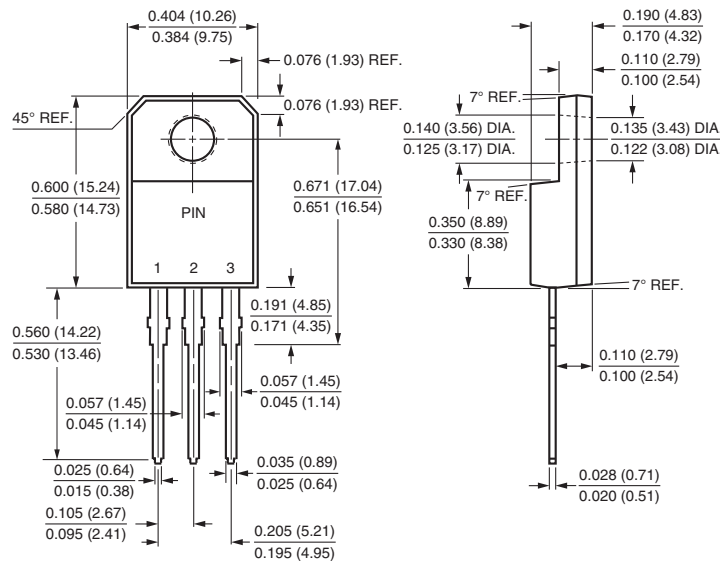


Fig. 4 - Typical Reverse Characteristics Per Diode

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

**ITO-220AB**





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